

# MCP6241/2

# 50 μA, 650 kHz Rail-to-Rail Op Amp

#### **Features**

• Gain Bandwidth Product: 650 kHz (typ.)

• Supply Current:  $I_Q = 50 \mu A \text{ (typ.)}$ 

• Supply Voltage: 1.8V to 5.5V

· Rail-to-Rail Input/Output

Extended Temperature Range: -40°C to +125°C

• Available in 5-pin SC-70 and SOT-23 packages

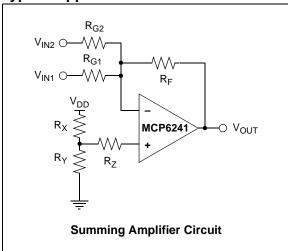
## **Applications**

- · Automotive
- · Portable Equipment
- · Photodiode (Transimpedance) Amplifier
- Analog Filters
- · Notebooks and PDAs
- · Battery-Powered Systems

### **Available Tools**

SPICE Macro Models (at www.microchip.com)
FilterLab® Software (at www.microchip.com)

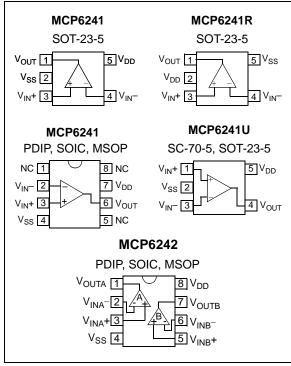
Typical Application



# Description

The Microchip Technology Inc. MCP6241/2 operational amplifiers (op amps) provide wide bandwidth for the quiescent current. The MCP6241/2 has a 650 kHz Gain Bandwidth Product (GBWP) and 77° (typ.) phase margin. This family operates from a single supply voltage as low as 1.8V, while drawing 50  $\mu A$  (typ.) quiescent current. In addition, the MCP6241/2 family supports rail-to-rail input and output swing, with a common mode input voltage range of  $V_{DD}$  + 300 mV to  $V_{SS}$  – 300 mV. These op amps are designed in one of Microchip's advanced CMOS processes.

# Package Types



# 1.0 ELECTRICAL CHARACTERISTICS

# **Absolute Maximum Ratings †**

V <sub>DD</sub> - V <sub>SS</sub>
All Inputs and Outputs $V_{SS}$ – 0.3V to $V_{DD}$ + 0.3V
Difference Input Voltage
Output Short Circuit Currentcontinuous
Current at Input Pins±2 mA
Current at Output and Supply Pins±30 mA
Storage Temperature65°C to +150°C
Maximum Junction Temperature (T <sub>J</sub> )+150°C
ESD Protection On All Pins (HBM;MM)≥ 4 kV; 200V

† Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

# **PIN FUNCTION TABLE**

Name	Function			
V <sub>IN</sub> +, V <sub>INA</sub> +, V <sub>INB</sub> +	Non-inverting Input			
V <sub>IN</sub> -, V <sub>INA</sub> -, V <sub>INB</sub> -	Inverting Input			
V <sub>DD</sub>	Positive Power Supply			
V <sub>SS</sub>	Negative Power Supply			
V <sub>OUT</sub> , V <sub>OUTA</sub> , V <sub>OUTB</sub>	Output			

# DC ELECTRICAL SPECIFICATIONS

**Electrical Characteristics**: Unless otherwise indicated,  $T_A = +25^{\circ}C$ ,  $V_{DD} = +1.8V$  to +5.5V,  $V_{SS} = GND$ ,  $V_{CM} = V_{DD}/2$ ,  $R_L = 100 \text{ k}\Omega$  to  $V_{DD}/2$  and  $V_{OUT} \approx V_{DD}/2$ .

to $v_{DD}/2$ and $v_{OUT} \approx v_{DD}/2$ .									
Parameters	Sym	Min	Тур	Max	Units	Conditions			
Input Offset									
Input Offset Voltage	Vos	-5.0	_	+5.0	mV	$V_{CM} = V_{SS}$			
Extended Temperature	$V_{OS}$	-7.0	_	+7.0	mV	$T_A = -40$ °C to +125°C, <b>(Note)</b>			
Input Offset Drift with Temperature	$\Delta V_{OS}/\Delta T_{A}$	_	±3.0	_	μV/°C	$T_A = -40$ °C to +125°C, $V_{CM} = V_{SS}$			
Power Supply Rejection	PSRR	_	83	_	dB	V <sub>CM</sub> = V <sub>SS</sub>			
Input Bias Current and Impedance									
Input Bias Current:	Ι <sub>Β</sub>	_	±1.0		pА				
At Temperature	I <sub>B</sub>	_	20	_	pA	T <sub>A</sub> = +85°C			
At Temperature	$I_{B}$	_	1100	_	pА	T <sub>A</sub> = +125°C			
Input Offset Current	I <sub>OS</sub>		±1.0		pА				
Common Mode Input Impedance	$Z_{CM}$	_	10 <sup>13</sup>   6	_	$\Omega  pF$				
Differential Input Impedance	$Z_{DIFF}$	_	10 <sup>13</sup>   3	_	$\Omega  pF$				
Common Mode									
Common Mode Input Range	$V_{CMR}$	$V_{SS} - 0.3$	_	$V_{DD} + 0.3$	٧				
Common Mode Rejection Ratio	CMRR	60	75	_	dB	$V_{CM} = -0.3V$ to 5.3V, $V_{DD} = 5V$			
Open-Loop Gain									
DC Open-Loop Gain (large signal)	A <sub>OL</sub>	90	110	_	dB	$V_{OUT} = 0.3V$ to $V_{DD} - 0.3V$ , $V_{CM} = V_{SS}$			
Output									
Maximum Output Voltage Swing	$V_{OL}, V_{OH}$	V <sub>SS</sub> + 35	_	V <sub>DD</sub> – 35	mV	$R_L = 10 \text{ k}\Omega$ , 0.5V Output Overdrive			
Output Short-Circuit Current	I <sub>SC</sub>	_	±6	_	mA	V <sub>DD</sub> = 1.8V			
	I <sub>SC</sub>	_	±23	_	mA	V <sub>DD</sub> = 5.5V			
Power Supply									
Supply Voltage	$V_{DD}$	1.8		5.5	V				
Quiescent Current per Amplifier	IQ	30	50	70	μΑ	$I_{O} = 0, V_{CM} = V_{DD} - 0.5V$			

**Note:** The SC-70 package is only tested at +25°C.

# **AC ELECTRICAL SPECIFICATIONS**

**Electrical Characteristics:** Unless otherwise indicated,  $T_A = +25$ °C,  $V_{DD} = +1.8$  to 5.5V,  $V_{SS} = GND$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L = 10$  kΩ to  $V_{DD}/2$  and  $C_L = 60$  pF.

Parameters	Sym	Min	Тур	Max	Units	Conditions
AC Response						
Gain Bandwidth Product	GBWP	_	650	_	kHz	
Phase Margin	PM	_	77	_	0	G = +1
Slew Rate	SR	_	0.30	_	V/µs	
Noise						
Input Noise Voltage	E <sub>ni</sub>	_	10	_	µVр-р	f = 0.1 Hz to 10 Hz
Input Noise Voltage Density	e <sub>ni</sub>	_	45	_	nV/√Hz	f = 1 kHz
Input Noise Current Density	i <sub>ni</sub>	_	0.6	_	fA/√Hz	f = 1 kHz

# **TEMPERATURE SPECIFICATIONS**

<b>Electrical Characteristics:</b> Unless otherwise indicated, $V_{DD} = +1.8V$ to +5.5V and $V_{SS} = GND$ .								
Parameters	Sym	Min	Тур	Max	Units	Conditions		
Temperature Ranges								
Extended Temperature Range	T <sub>A</sub>	-40	_	+125	°C			
Operating Temperature Range	T <sub>A</sub>	-40	_	+125	°C	(Note)		
Storage Temperature Range	T <sub>A</sub>	-65	_	+150	°C			
Thermal Package Resistances								
Thermal Resistance, 5L-SC70	$\theta_{JA}$	_	331	_	°C/W			
Thermal Resistance, 5L-SOT-23	$\theta_{JA}$	_	256	_	°C/W			
Thermal Resistance, 8L-PDIP	$\theta_{JA}$	_	85	_	°C/W			
Thermal Resistance, 8L-SOIC	$\theta_{JA}$	_	163	_	°C/W			
Thermal Resistance, 8L-MSOP	$\theta_{JA}$	_	206	_	°C/W			

Note: The internal Junction Temperature (T<sub>J</sub>) must not exceed the Absolute Maximum specification of +150°C.

# 2.0 TYPICAL PERFORMANCE CURVES

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

**Note:** Unless otherwise indicated,  $T_A = +25$ °C,  $V_{DD} = +1.8V$  to +5.5V,  $V_{SS} = GND$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L = 100 \text{ k}\Omega$  to  $V_{DD}/2$  and  $C_L = 60 \text{ pF}$ .

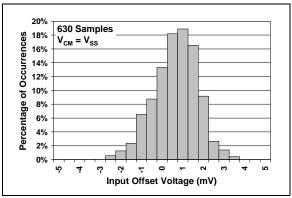
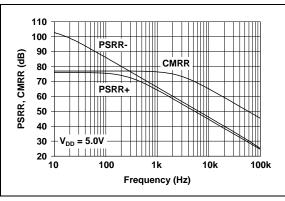


FIGURE 2-1: Input Offset Voltage.



**FIGURE 2-2:** PSRR, CMRR vs. Frequency.

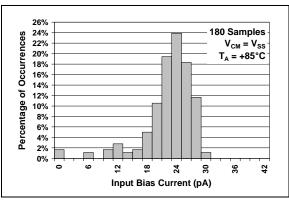


FIGURE 2-3: Input Bias Current at +85°C.

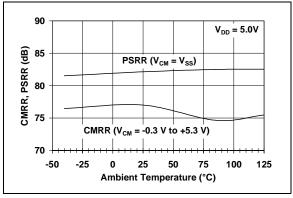
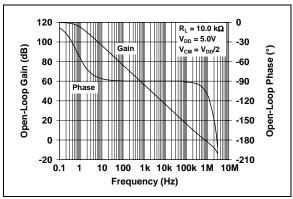


FIGURE 2-4: CMRR, PSRR vs. Ambient Temperature.



**FIGURE 2-5:** Open-Loop Gain, Phase vs. Frequency.

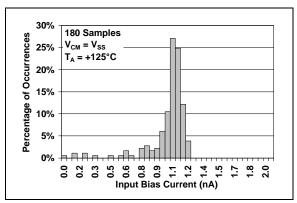
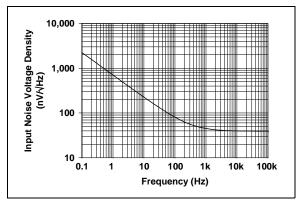
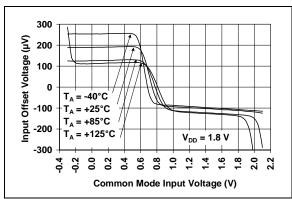


FIGURE 2-6: Input Bias Current at +125°C.

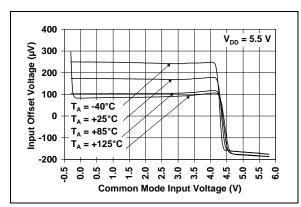
**Note:** Unless otherwise indicated,  $T_A$  = +25°C,  $V_{DD}$  = +1.8V to +5.5V,  $V_{SS}$  = GND,  $V_{CM}$  =  $V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L$  = 100 k $\Omega$  to  $V_{DD}/2$  and  $C_L$  = 60 pF.



**FIGURE 2-7:** Input Noise Voltage Density vs. Frequency.



**FIGURE 2-8:** Input Offset Voltage vs. Common Mode Input Voltage at  $V_{DD} = 1.8V$ .



**FIGURE 2-9:** Input Offset Voltage vs. Common Mode Input Voltage at  $V_{DD} = 5.5V$ .

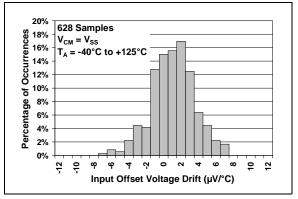


FIGURE 2-10: Input Offset Voltage Drift.

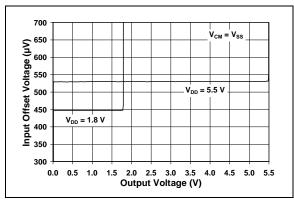
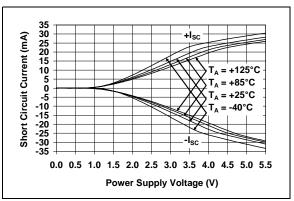
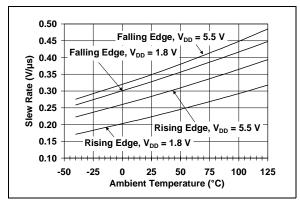


FIGURE 2-11: Input Offset Voltage vs. Output Voltage.

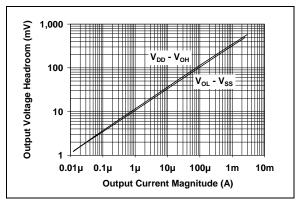


**FIGURE 2-12:** Output Short-Circuit Current vs. Ambient Temperature.

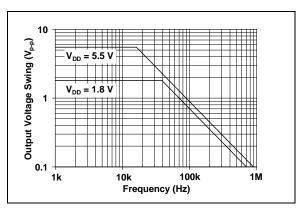
**Note:** Unless otherwise indicated,  $T_A$  = +25°C,  $V_{DD}$  = +1.8V to +5.5V,  $V_{SS}$  = GND,  $V_{CM}$  =  $V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L$  = 100 k $\Omega$  to  $V_{DD}/2$  and  $C_L$  = 60 pF.



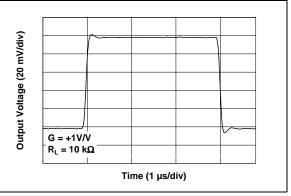
**FIGURE 2-13:** Slew Rate vs. Ambient Temperature.



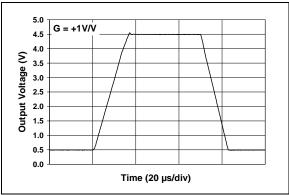
**FIGURE 2-14:** Output Voltage Headroom vs. Output Current Magnitude.



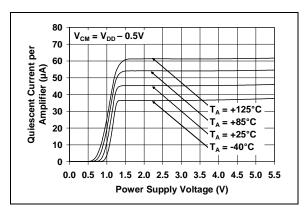
**FIGURE 2-15:** Output Voltage Swing vs. Frequency.



**FIGURE 2-16:** Small Signal Non-Inverting Pulse Response.



**FIGURE 2-17:** Large Signal Non-Inverting Pulse Response.



**FIGURE 2-18:** Quiescent Current vs. Power Supply Voltage.

# 3.0 APPLICATION INFORMATION

The MCP6241/2 family of op amps is manufactured using Microchip's state-of-the-art CMOS process and is specifically designed for low-power and general-purpose applications. The low supply voltage, low quiescent current and wide bandwidth makes the MCP6241/2 ideal for battery-powered applications.

# 3.1 Rail-to-Rail Input

The MCP6241/2 op amps are designed to prevent phase reversal when the input pins exceed the supply voltages. Figure 3-1 shows the input voltage exceeding the supply voltage without any phase reversal.

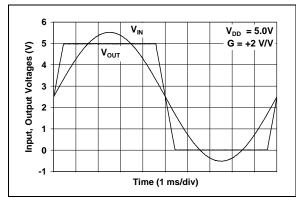
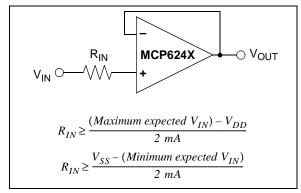


FIGURE 3-1: The MCP6241/2 Show No Phase Reversal.

The input stage of the MCP6241/2 op amps use two differential input stages in parallel. One operates at low common mode input voltage (V<sub>CM</sub>) and the other at high V<sub>CM</sub>. With this topology, the device operates with V<sub>CM</sub> up to 300 mV above V<sub>DD</sub> and 300 mV below V<sub>SS</sub>. The Input Offset Voltage is measured at V<sub>CM</sub> = V<sub>SS</sub> – 300 mV and V<sub>DD</sub> + 300 mV to ensure proper operation.

Input voltages that exceed the input voltage range  $(V_{SS}-0.3V \text{ to } V_{DD}+0.3V \text{ at } 25^{\circ}\text{C})$  can cause excessive current to flow into or out of the input pins. Current beyond ±2 mA can cause reliability problems. Applications that exceed this rating must be externally limited with a resistor, as shown in Figure 3-2.



**FIGURE 3-2:** Input Current-Limiting Resistor  $(R_{IN})$ .

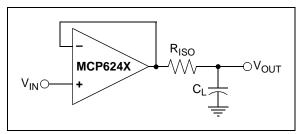
## 3.2 Rail-to-Rail Output

The output voltage range of the MCP6241/2 op amps is  $V_{DD}-35$  mV (min.) and  $V_{SS}+35$  mV (max.) when  $R_L=100~k\Omega$  is connected to  $V_{DD}/2$  and  $V_{DD}=5.5$ V. Refer to Figure 2-14 for more information.

# 3.3 Capacitive Loads

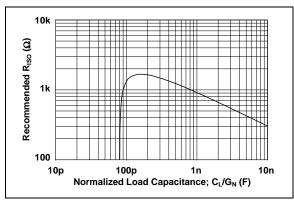
Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases and the closed-loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. A unity-gain buffer (G=+1) is the most sensitive to capacitive loads, but all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g.,  $> 100 \ pF$  when G = +1), a small series resistor at the output (R<sub>ISO</sub> in Figure 3-3) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. It does not, however, improve the bandwidth.



**FIGURE 3-3:** Output resistor,  $R_{ISO}$  stabilizes large capacitive loads.

Figure 3-4 gives recommended  $R_{ISO}$  values for different capacitive loads and gains. The x-axis is the normalized load capacitance ( $C_L/G_N$ ), where  $G_N$  is the circuit's noise gain. For non-inverting gains,  $G_N$  and the gain are equal. For inverting gains,  $G_N$  is 1 + |Gain| (e.g., -1 V/V gives  $G_N$  = +2 V/V).



**FIGURE 3-4:** Recommended R<sub>ISO</sub> Values for Capacitive Loads.

After selecting  $R_{\rm ISO}$  for your circuit, double-check the resulting frequency response peaking and step response overshoot. Evaluation on the bench and simulations with the MCP6241/2 SPICE macro model are very helpful. Modify  $R_{\rm ISO}$ 's value until the response is reasonable.

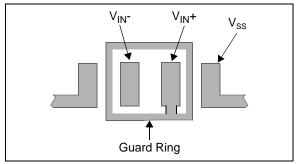
# 3.4 Supply Bypass

With this op amp, the power supply pin ( $V_{DD}$  for single-supply) should have a local bypass capacitor (i.e., 0.01  $\mu F$  to 0.1  $\mu F$ ) within 2 mm for good high-frequency performance. It also needs a bulk capacitor (i.e., 1  $\mu F$  or larger) within 100 mm to provide large, slow currents. This bulk capacitor can be shared with other parts.

## 3.5 PCB Surface Leakage

In applications where low input bias current is critical, PCB (printed circuit board) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is  $10^{12}\Omega$ . A 5V difference would cause 5 pA, if current-to-flow. This is greater than the MCP6241/2 family's bias current at 25°C (1 pA, typ).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 3-5.



**FIGURE 3-5:** Example Guard Ring Layout for Inverting Gain.

- 1. Non-inverting Gain and Unity-Gain Buffer:
  - Connect the non-inverting pin (V<sub>IN</sub>+) to the input with a wire that does not touch the PCB surface.
  - Connect the guard ring to the inverting input pin (V<sub>IN</sub>-). This biases the guard ring to the common mode input voltage.
- Inverting and transimpedance gain amplifiers (convert current to voltage, such as photo detectors):
  - a. Connect the guard ring to the non-inverting input pin (V<sub>IN</sub>+). This biases the guard ring to the same reference voltage as the op amp (e.g., V<sub>DD</sub>/2 or ground).
  - Connect the inverting pin (V<sub>IN</sub>-) to the input with a wire that does not touch the PCB surface.

# 4.0 APPLICATION CIRCUITS

# 4.1 Matching the Impedance at the Inputs

To minimize the effect of offset voltage in an amplifier circuit, the impedance at both inverting and non-inverting inputs needs to be matched. This is done by choosing the circuit resistor values so that the total resistance at each input is the same. Figure 4-1 shows a summing amplifier circuit.

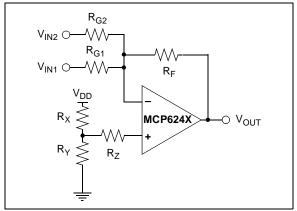


FIGURE 4-1: Summing Amplifier Circuit.

To match the inputs, set all voltage sources to ground and calculate the total resistance at the input nodes. In this summing amplifier circuit, the resistance at the inverting input is calculated by setting  $V_{IN1}$ ,  $V_{IN2}$  and  $V_{OUT}$  to ground. In this case,  $R_{G1}$ ,  $R_{G2}$  and  $R_F$  are in parallel. The total resistance at the inverting input is:

$$R_{VIN^{-}} = \frac{1}{\left(\frac{1}{R_{GI}} + \frac{1}{R_{G2}} + \frac{1}{R_{F}}\right)}$$

Where:

R<sub>VIN</sub>- = total resistance at the inverting input

At the non-inverting input,  $V_{DD}$  is the only voltage source. When  $V_{DD}$  is set to ground, both  $R_X$  and  $R_Y$  are in parallel. The total resistance at the non-inverting input is:

$$R_{VIN^{+}} = \frac{1}{\left(\frac{1}{R_X} + \frac{1}{R_Y}\right)} + R_Z$$

Where:

R<sub>VIN</sub>+ = total resistance at the inverting input

To minimize offset voltage and increase circuit accuracy, the resistor values need to meet the condition:

$$R_{VIN^+} = R_{VIN^-}$$

# 4.2 Compensating for the Parasitic Capacitance

In analog circuit design, the PCB parasitic capacitance can compromise the circuit behavior; Figure 4-2 shows a typical scenario. If the input of an amplifier sees parasitic capacitance of several picofarad ( $C_{PARA}$ , which includes the common mode capacitance of 6 pF, typical) and large RF and RG, the frequency response of the circuit will include a zero. This parasitic zero introduces gain peaking and can cause circuit instability.

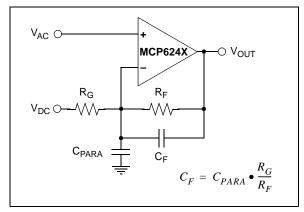


FIGURE 4-2: Effect of Parasitic Capacitance at the Input.

One solution is to use smaller resistor values to push the zero to a higher frequency. Another solution is to compensate by introducing a pole at the point at which the zero occurs. This can be done by adding  $C_F$  in parallel with the feedback resistor  $(R_F).\ C_F$  needs to be selected so that the ratio  $C_{PARA}:C_F$  is equal to the ratio of  $R_F:R_{G^*}$ 

### 5.0 DESIGN TOOLS

Microchip provides the basic design tools needed for the MCP6241/2 family of op amps.

#### 5.1 SPICE Macro Model

The latest SPICE macro model for the MCP6241/2 op amps is available on our web site at www.microchip.com. This model is intended to be an initial design tool that works well in the op amp's linear region of operation at room temperature. See the model file for information on its capabilities.

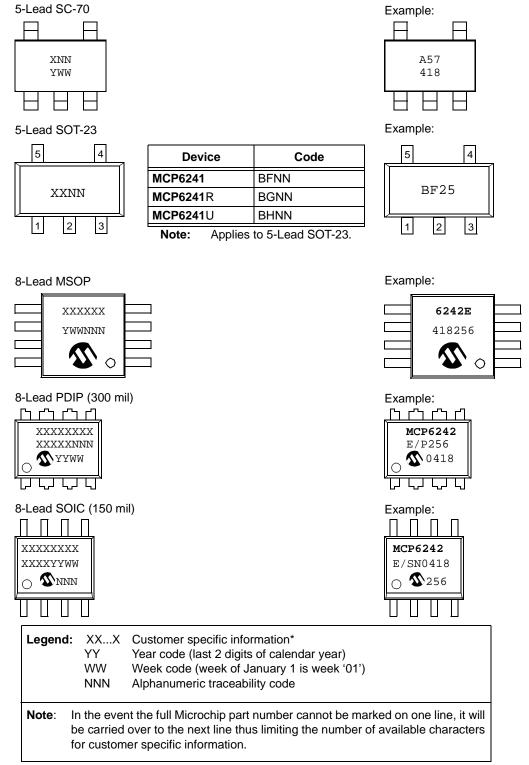
Bench testing is a very important part of any design and cannot be replaced with simulations. Also, simulation results using this macro model need to be validated by comparing them to the data sheet specifications and characteristic curves.

# 5.2 FilterLab<sup>®</sup> Software

The FilterLab software is an innovative tool that simplifies analog active-filter (using op amps) design. Available free of charge from our web site at www.microchip.com, the FilterLab software active-filter design tool provides full schematic diagrams of the filter circuit with component values. It also outputs the filter circuit in SPICE format, which can be used with the macro model to simulate actual filter performance.

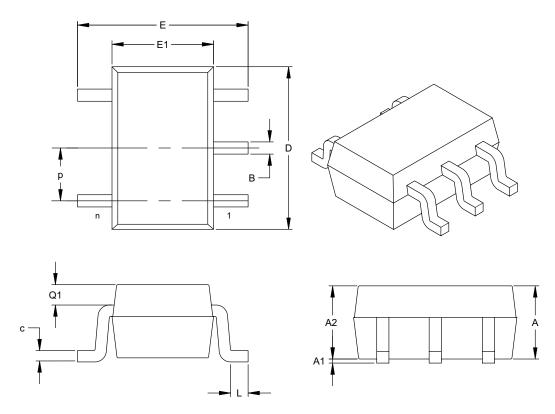
### 6.0 PACKAGING INFORMATION

# 6.1 Package Marking Information



<sup>\*</sup> Standard marking consists of Microchip part number, year code, week code, traceability code (facility code, mask rev#, and assembly code). For marking beyond this, certain price adders apply. Please check with your Microchip Sales Office.

# 5-Lead Plastic Small Outline Transistor Package (LT) (SC-70)



	Units		INCHES			MILLIMETERS*		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		5			5		
Pitch	р		.026 (BSC)			0.65 (BSC)		
Overall Height	Α	.031		.043	0.80		1.10	
Molded Package Thickness	A2	.031		.039	0.80		1.00	
Standoff	A1	.000		.004	0.00		0.10	
Overall Width	E	.071		.094	1.80		2.40	
Molded Package Width	E1	.045		.053	1.15		1.35	
Overall Length	D	.071		.087	1.80		2.20	
Foot Length	L	.004		.012	0.10		0.30	
Top of Molded Pkg to Lead Shoulder	Q1	.004		.016	0.10		0.40	
Lead Thickness	С	.004		.007	0.10		0.18	
Lead Width	В	.006		.012	0.15		0.30	

<sup>\*</sup>Controlling Parameter

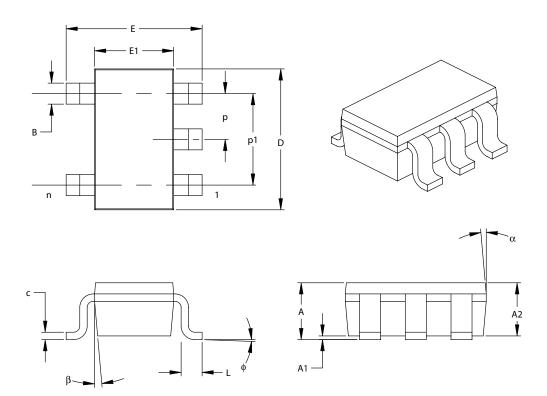
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

JEITA (EIAJ) Standard: SC-70

Drawing No. C04-061

# 5-Lead Plastic Small Outline Transistor (OT) (SOT23)



	Units	INCHES*			N		
Dimension Lim	its	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		5			5	
Pitch	р		.038			0.95	
Outside lead pitch (basic)	p1		.075			1.90	
Overall Height	Α	.035	.046	.057	0.90	1.18	1.45
Molded Package Thickness	A2	.035	.043	.051	0.90	1.10	1.30
Standoff	A1	.000	.003	.006	0.00	0.08	0.15
Overall Width	Е	.102	.110	.118	2.60	2.80	3.00
Molded Package Width	E1	.059	.064	.069	1.50	1.63	1.75
Overall Length	D	.110	.116	.122	2.80	2.95	3.10
Foot Length	L	.014	.018	.022	0.35	0.45	0.55
Foot Angle	ф	0	5	10	0	5	10
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20
Lead Width	В	.014	.017	.020	0.35	0.43	0.50
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

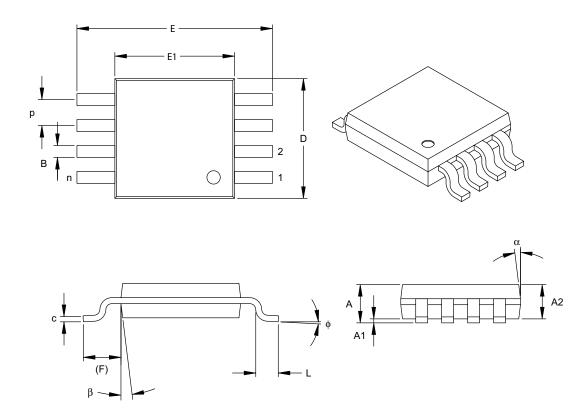
<sup>\*</sup>Controlling Parameter

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

EIAJ Equivalent: SC-74A Drawing No. C04-091

# 8-Lead Plastic Micro Small Outline Package (MS) (MSOP)



	Units	INCHES			М	*	
Dimension Lin	nits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.026 BSC			0.65 BSC	
Overall Height	Α	-	-	.043	-	-	1.10
Molded Package Thickness	A2	.030	.033	.037	0.75	0.85	0.95
Standoff	A1	.000	-	.006	0.00	-	0.15
Overall Width	E		.193 TYP.			4.90 BSC	
Molded Package Width	E1		.118 BSC			3.00 BSC	
Overall Length	D		.118 BSC		3.00 BSC		
Foot Length	L	.016	.024	.031	0.40	0.60	0.80
Footprint (Reference)	F		.037 REF			0.95 REF	
Foot Angle	ф	0°	-	8°	0°	-	8°
Lead Thickness	С	.003	.006	.009	0.08	-	0.23
Lead Width	В	.009	.012	.016	0.22	-	0.40
Mold Draft Angle Top	α	5°	-	15°	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°	5°	-	15°

<sup>\*</sup>Controlling Parameter

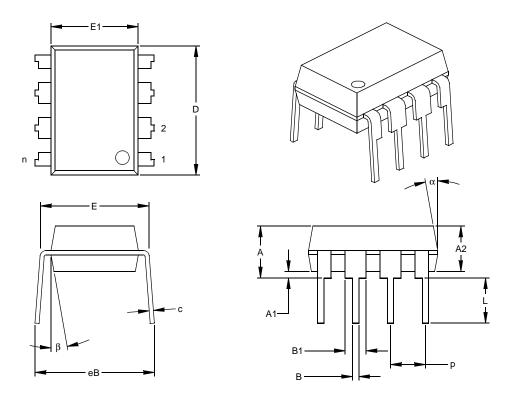
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MO-187

Drawing No. C04-111

# 8-Lead Plastic Dual In-line (P) - 300 mil (PDIP)



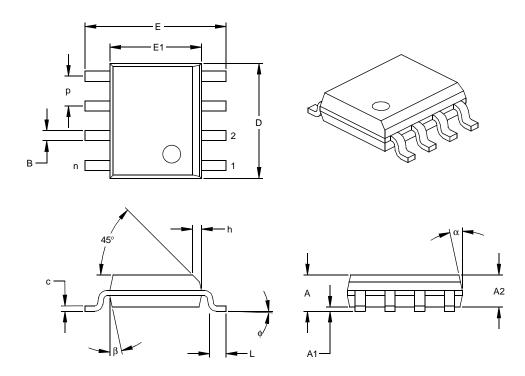
	Units		INCHES*			MILLIMETERS		
Dimensi	ion Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		8			8		
Pitch	р		.100			2.54		
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32	
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26	
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60	
Overall Length	D	.360	.373	.385	9.14	9.46	9.78	
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing	§ eB	.310	.370	.430	7.87	9.40	10.92	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

Notes:
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-001
Drawing No. C04-018

<sup>\*</sup> Controlling Parameter § Significant Characteristic

# 8-Lead Plastic Small Outline (SN) - Narrow, 150 mil (SOIC)



	Units	INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side.
JEDEC Equivalent: MS-012
Drawing No. C04-057

<sup>\*</sup> Controlling Parameter § Significant Characteristic

# PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u>-X</u>	<u>/XX</u>	E	camples:	
•	 nd Reel Temperat d/or Range	•	a)	MCP6241-E/SN:	Extended Temp., 8LD SOIC pkg.
	d/or Range e Pinout		b)	MCP6241-E/MS:	Extended Temp., 8LD MSOP pkg.
Device:		Op Amp (MSOP, PDIP, SOIC) Op Amp (Tape and Reel) (SOT-23)	c)	MCP6241-E/P:	Extended Temp., 8LD PDIP pkg.
	MCP6241RT: Single MCP6241UT: Single (SC-70	Op Amp (Tape and Reel) (SOT-23) Op Amp (Tape and Reel) O, SOT-23)		MCP6241RT-E/OT:	Tape and Reel, Extended Temp., 5LD SOT-23 pkg
	MCP6242T: Dual C	Op Amp (MSOP, PDIP, SOIC) Op Amp (Tape and Reel)	e)	MCP6241UT-E/OT:	
Temperature Range:	$E = -40^{\circ}C \text{ to } +125^{\circ}C$		f)	MCP6241UT-E/LT:	Tape and Reel, Extended Temp.,
Package:	MS = Plastic Micro Si P = Plastic DIP (300 OT = Plastic Small O	e (SC-70), 5-lead (MCP6241U only) mall Outline (MSOP), 8-lead 0 mil Body), 8-lead utline Transistor (SOT-23), 5-lead :P6241R, MCP6241U) 150 mil Body). 8-lead	g)	MCP6241T-E/OT:	5LD SC-70 pkg. Tape and Reel, Extended Temp., 5LD SOT-23 pkg.
		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	a)	MCP6242-E/SN:	Extended Temp., 8LD SOIC pkg.
			b)	MCP6242-E/MS:	Extended Temp., 8LD MSOP pkg.
			c)	MCP6242-E/P:	Extended Temp., 8LD PDIP pkg.
			d)	MCP6242T-E/SN:	Tape and Reel, Extended Temp., 8LD SOIC pkg.

# **Sales and Support**

### **Data Sheets**

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

- 1. Your local Microchip sales office
- 2. The Microchip Corporate Literature Center U.S. FAX: (480) 792-7277
- 3. The Microchip Worldwide Site (www.microchip.com)

Please specify which device, revision of silicon and Data Sheet (include Literature #) you are using.

#### **Customer Notification System**

Register on our web site (www.microchip.com/cn) to receive the most current information on our products.

# MCP6241/2

NOTES:

#### Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not
  mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is intended through suggestion only and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. No representation or warranty is given and no liability is assumed by Microchip Technology Incorporated with respect to the accuracy or use of such information, or infringement of patents or other intellectual property rights arising from such use or otherwise. Use of Microchip's products as critical components in life support systems is not authorized except with express written approval by Microchip. No licenses are conveyed, implicitly or otherwise, under any intellectual property rights.

#### **Trademarks**

The Microchip name and logo, the Microchip logo, Accuron, dsPIC, KEELOQ, microID, MPLAB, PIC, PICmicro, PICSTART, PRO MATE, PowerSmart, rfPIC, and SmartShunt are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

AmpLab, FilterLab, MXDEV, MXLAB, PICMASTER, SEEVAL, SmartSensor and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, Application Maestro, dsPICDEM, dsPICDEM.net, dsPICworks, ECAN, ECONOMONITOR, FanSense, FlexROM, fuzzyLAB, In-Circuit Serial Programming, ICSP, ICEPIC, Migratable Memory, MPASM, MPLIB, MPLINK, MPSIM, PICkit, PICDEM, PICDEM.net, PICLAB, PICtail, PowerCal, PowerInfo, PowerMate, PowerTool, rfLAB, rfPICDEM, Select Mode, Smart Serial, SmartTel and Total Endurance are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

 $\ensuremath{\mathsf{SQTP}}$  is a service mark of Microchip Technology Incorporated in the U.S.A.

All other trademarks mentioned herein are property of their respective companies.

© 2004, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

Printed on recycled paper.

QUALITY MANAGEMENT SYSTEM

CERTIFIED BY DNV

ISO/TS 16949:2002 ===

Microchip received ISO/TS-16949:2002 quality system certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona and Mountain View, California in October 2003. The Company's quality system processes and procedures are for its PICmicro® 8-bit MCUs, KEELoo® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



# WORLDWIDE SALES AND SERVICE

#### **AMERICAS**

**Corporate Office** 

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277

Technical Support: 480-792-7627 Web Address: www.microchip.com

Alpharetta, GA 30022 Tel: 770-640-0034 Fax: 770-640-0307

**Boston** 

Westford, MA 01886 Tel: 978-692-3848 Fax: 978-692-3821

Chicago

Itasca, IL 60143 Tel: 630-285-0071 Fax: 630-285-0075

**Dallas** 

Addison Plaza Addison, TX 75001 Tel: 972-818-7423 Fax: 972-818-2924

**Detroit** 

Tri-Atria Office Building Farmington Hills, MI 48334 Tel: 248-538-2250

Fax: 248-538-2260

Kokomo

Kokomo, IN 46902 Tel: 765-864-8360 Fax: 765-864-8387

Los Angeles

Mission Viejo, CA 92691 Tel: 949-462-9523 Fax: 949-462-9608

San Jose

Mountain View, CA 94043 Tel: 650-215-1444 Fax: 650-961-0286

**Toronto** 

Mississauga, Ontario L4V 1X5, Canada Tel: 905-673-0699

Fax: 905-673-6509

ASIA/PACIFIC

Australia

Microchip Technology Australia Pty Ltd Sydney, Australia Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing

Wan Tai Bei Hai Bldg. Beijing, 100027, China Tel: 86-10-85282100 Fax: 86-10-85282104

China - Chengdu

Ming Xing Financial Tower Chengdu 610016, China Tel: 86-28-86766200 Fax: 86-28-86766599

China - Fuzhou

World Trade Plaza Fuzhou 350001. China Tel: 86-591-7503506 Fax: 86-591-7503521

China - Hong Kong SAR

Metroplaza Kwai Fong, N.T., Hong Kong Tel: 852-2401-1200 Fax: 852-2401-3431

China - Shanghai

Far East International Plaza Shanghai, 200051 Tel: 86-21-6275-5700 Fax: 86-21-6275-5060

China - Shenzhen

United Plaza Shenzhen 518033, China Tel: 86-755-82901380 Fax: 86-755-8295-1393

China - Shunde

Foshan City, Guangdong 528303, China Tel: 86-757-28395507

Fax: 86-757-28395571

China - Qingdao

Fullhope Plaza, Qingdao 266071, China Tel: 86-532-5027355 Fax: 86-532-5027205

India

Divyasree Chambers Bangalore, 560 025, India Tel: 91-80-22290061 Fax: 91-80-22290062

International Trade Tower New Delhi, 110019, India Tel: +91-11-5160-8632 Fax: +91-11-5160-8632

Japan

Yokohama, Kanagawa, 222-0033, Japan Tel: 81-45-471- 6166

Fax: 81-45-471-6122

Samsung-Dong, Kangnam-Ku Seoul, Korea 135-882 Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Singapore

Singapore, 188980 Tel: 65-6334-8870 Fax: 65-6334-8850 Taiwan

Kaohsiung Branch Kaohsiung 806, Taiwan Tel: 886-7-536-4816 Fax: 886-7-536-4817

Taiwan

Taiwan Branch Taipei City, 104, Taiwan Tel: 886-2-2500-6610 Fax: 886-2-2508-0102

Taiwan Branch Hsinchu City 300, Taiwan Tel: 886-3-572-9526 Fax: 886-3-572-6459

**EUROPE** 

Austria

Austria

Tel: 43-7242-2244-399 Fax: 43-7242-2244-393

Denmark

Regus Business Centre Ballerup DK-2750 Denmark

Tel: 45-4420-9895 Fax: 45-4420-9910

France

91300 Massy, France Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany

D-85737 Ismaning, Germany Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Italy

Milan, Italy Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands

NL-5152 JR, Drunen, Netherlands Tel: 31-416-690399

Fax: 31-416-690340

**United Kingdom** 

Wokingham Berkshire, England RG41 5TU Tel: 44-118-921-5869

Fax: 44-118-921-5820

08/16/04

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

# Microchip:

<u>MCP6242-E/MS</u> <u>MCP6242-E/SN</u> <u>MCP6241-E/MS</u> <u>MCP6241-E/SN</u> <u>MCP6241-E/P</u> <u>MCP6241-E/P</u> <u>MCP6241-E/P</u> <u>MCP6241-E/P</u> <u>MCP6241-E/SN</u> <u>MCP6241T-E/SN</u> <u>MCP6241T-E/SN</u> <u>MCP6241T-E/OT</u> <u>MCP6241T-E/OT</u> <u>MCP6241T-E/OT</u>